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## NTE2553 Silicon NPN Transistor Darlington, Motor Driver, Switch TO-220 Full Pack

**Features:**

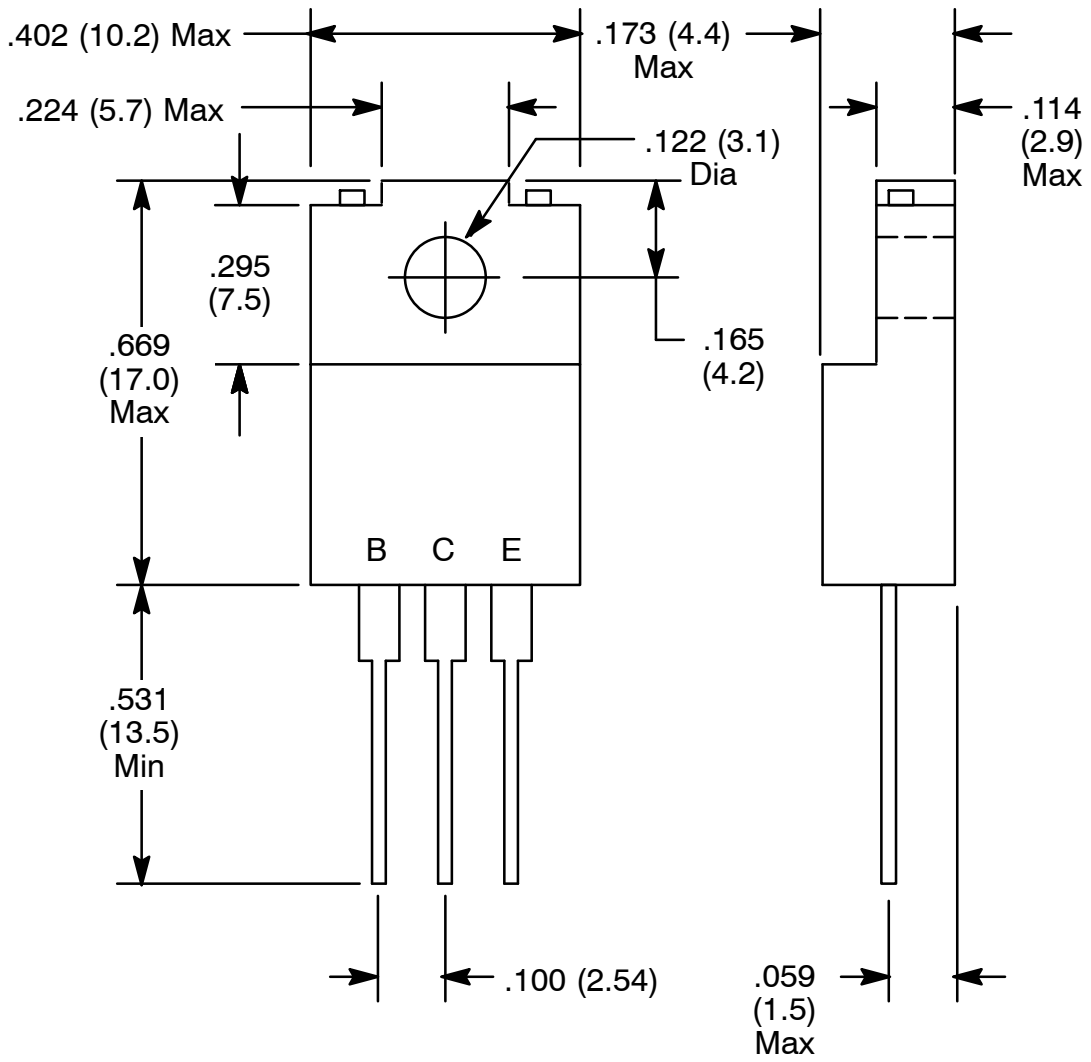
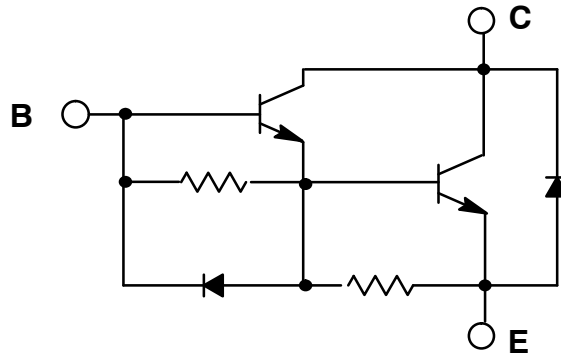
- High DC Current Gain
- High Breakdown Voltage

**Absolute Maximum Ratings:** ( $T_A = +25^\circ\text{C}$  unless otherwise specified)

Collector-Base Voltage, $V_{CBO}$ .....	300V
Collector-Emitter Voltage, $V_{CEO}$ .....	200V
Emitter-Base Voltage, $V_{EBO}$ .....	6V
Collector Current, $I_C$	
Continuous .....	±12A
Peak .....	±18A
Base Current, $I_B$ .....	1A
Collector Power Dissipation, $P_C$	
$T_A = +25^\circ\text{C}$ .....	2W
$T_C = +25^\circ\text{C}$ .....	30W
Operating Junction Temperature, $T_J$ .....	+150°C
Storage Temperature Range, $T_{stg}$ .....	-55° to +150°C

**Electrical Characteristics:** ( $T_A = +25^\circ\text{C}$  unless otherwise specified)

Parameter	Symbol	Test Conditions	Min	Typ	Max	Unit
Collector Cut-Off Current	$I_{CBO}$	$V_{CB} = 300V, I_E = 0$	-	-	100	$\mu\text{A}$
Emitter Cut-Off Current	$I_{EBO}$	$V_{EB} = 6V, I_C = 0$	50	-	150	mA
Collector-Base Breakdown Voltage	$V_{(BR)CBO}$	$I_C = 1mA, I_E = 0$	300	-	-	V
Collector-Emitter Sustaining Voltage	$V_{CEO(sus)}$	$I_C = 250mA, L 40mH$	200	-	-	V
DC Current Gain	$h_{FE}$	$V_{CE} = 2V, I_C = 5A$	500	-	5000	
		$V_{CE} = 2V, I_C = 10A$	100	-	-	
Collector-Emitter Saturation Voltage	$V_{CE(sat)}$	$I_C = 10A, I_B = 100mA$	-	-	2.0	V
Base-Emitter Saturation Voltage	$V_{BE(sat)}$	$I_C = 10A, I_B = 100mA$	-	-	2.3	V
Emitter-Collector Forward Voltage	$V_{ECF}$	$I_E = 10A, I_B = 0$	-	1.5	2.0	V
Transition Frequency	$f_T$	$V_{CE} = 2V, I_C = 1A$	-	40	-	MHz
Collector Output Capacitance	$C_{ob}$	$V_{CB} = 10V, I_E = 0, f = 1MHz$	-	200	-	pF
Turn-On Time	$t_{on}$	$V_{CC} = 100V,$ $I_{B1} = -I_{B2} = 100mA$	-	-	1.0	$\mu\text{s}$
Storage Time	$t_{stg}$		-	-	12	$\mu\text{s}$
Fall Time	$t_f$		-	-	2.0	$\mu\text{s}$



**NOTE:** Tab is isolated